VS-150EBU04HF4

Vishay Semiconductors

Ultrafast Soft Recovery Diode, 150 A FRED Pt®



PowerTab[®]

PRODUCT SUMMARY					
Package	PowerTab [®]				
I _{F(AV)}	150 A				
V _R	400 V				
V _F at I _F	0.9 V				
t _{rr} (typ.)	See recovery table				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		400	V	
Continuous forward current	I _{F(AV)}	T _C = 104 °C	150		
Single pulse forward current	I _{FSM}	T _C = 25 °C	1500	А	
Maximum repetitive forward current	I _{FRM}	Square wave, 20 kHz	300		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	MBOL TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 200 μA	400	-	-		
		I _F = 150 A	-	1.07	1.3	v	
Forward voltage	V _F	I _F = 150 A, T _J = 175 °C	-	0.9	1.1		
		I _F = 150 A, T _J = 125 °C	-	0.96	1.17		
Reverse leakage current		V _R = V _R rated	-	-	50	μA	
neverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	4	mA	
Junction capacitance	CT	V _R = 400 V - 100		100	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body - 3.5 -		nH			

Revision: 16-Jun-15

Document Number: 93995

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1



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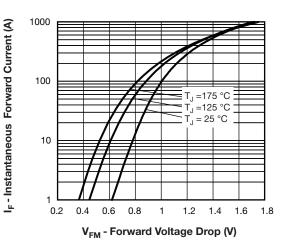
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
Boyono rocovory timo	+	T _J = 25 °C		-	93	-	20	
Reverse recovery time	t _{rr}	T _J = 125 °C	I _F = 150 A V _R = 200 V dI _F /dt = 200 A/μs	-	172	-	ns	
		T _J = 25 °C		-	11	-	A	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	20	-		
Reverse recovery charge	0	T _J = 25 °C		-	490	-		
	Q _{rr}	T _J = 125 °C		-	1740	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction to case	R _{thJC}		-	-	0.35	K/W	
Thermal resistance, junction to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	r./ vv	
Weight			-	-	5.02	g	
weight			-	0.18	-	oz.	
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)	
Marking device		Case style PowerTab®		150EE	3U04H		

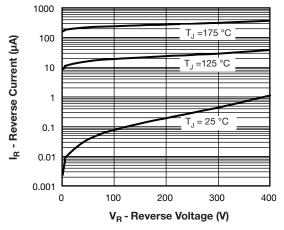
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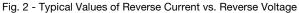
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Fig. 1 - Maximum Forward Voltage Drop Characteristics





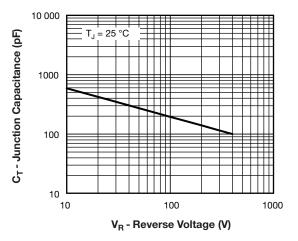


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

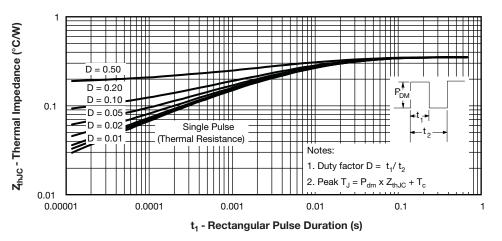


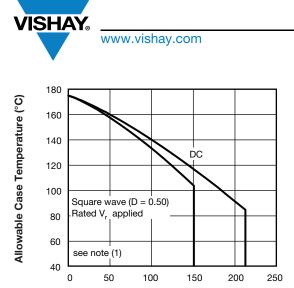
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

 Revision: 16-Jun-15
 3
 Document Number: 93995

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I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

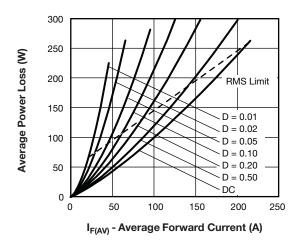


Fig. 6 - Forward Power Loss Characteristics

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = Rated V_R

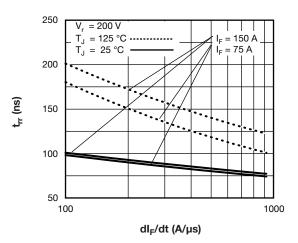
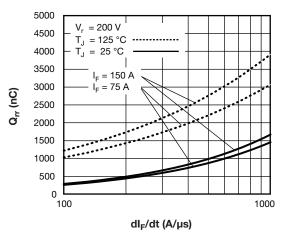
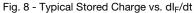


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt





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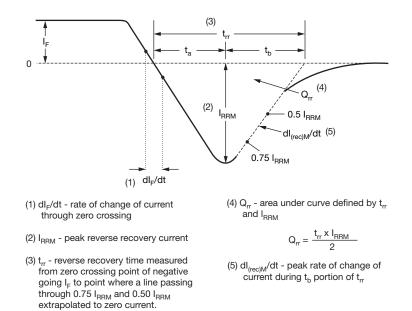


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	150	Е	В	U	04	н	F4
	1	2	3	4	5	6	7	8
	1 - 2 - 3 -	Cur	,	niconduc ng (150 e				
	4 - 5 -		verTab [®] afast reo					
	6 - 7 -		Voltage rating (04 = 400 V) H = AEC-Q101 qualified					
	8 -	- Env	ironmer	ntal digit	:			

F4 = RoHS-compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-150EBU04HF4	25	375	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95467				
Application note	www.vishay.com/doc?95179				
SPICE model	www.vishay.com/doc?95623				

Revision: 16-Jun-15

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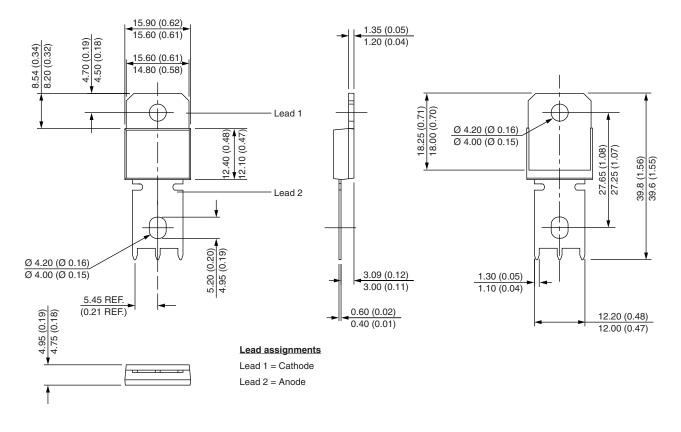
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DIMENSIONS in millimeters (inches)





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